



查询HMC473MS8供应商

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HMC473MS8

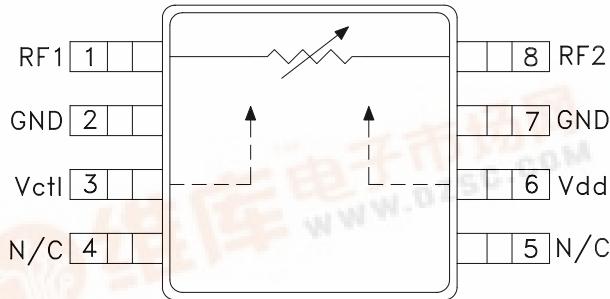
GaAs MMIC VOLTAGE-VARIABLE ATTENUATOR, 0.45 - 2.2 GHz

Typical Applications

The HMC473MS8 is ideal for:

- Cellular, UMTS/3G Infrastructure
- Portable Wireless
- GPS

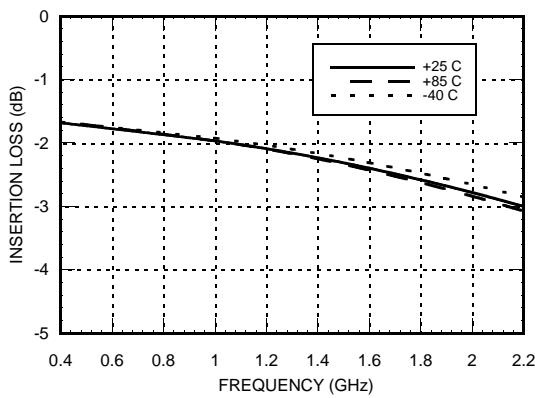
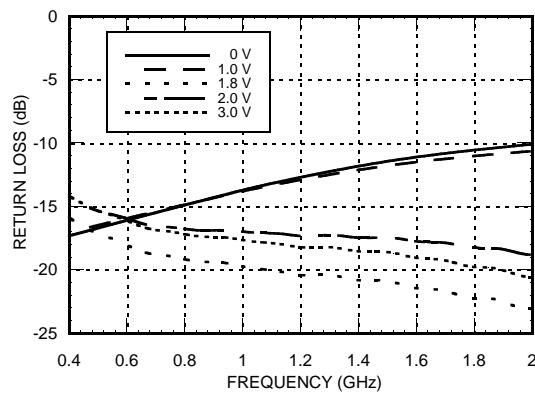
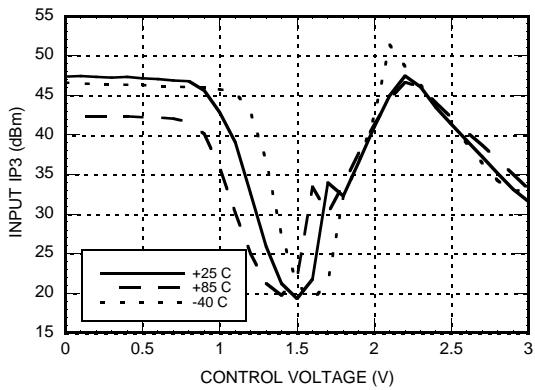
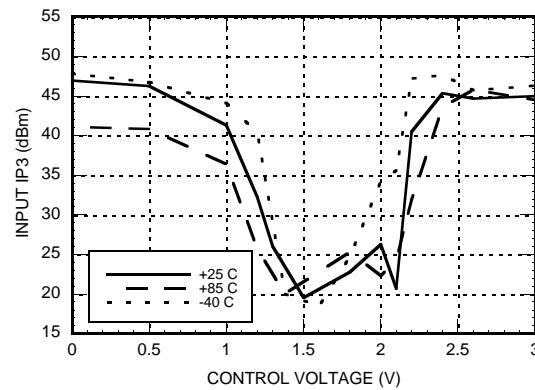
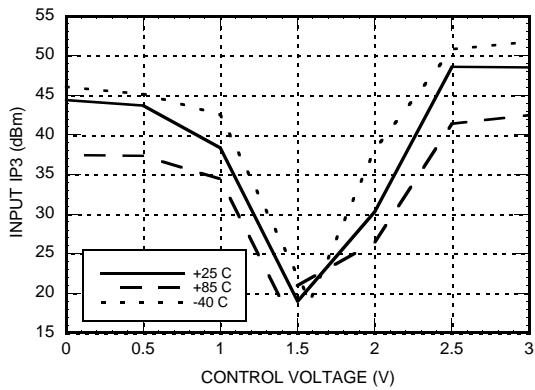
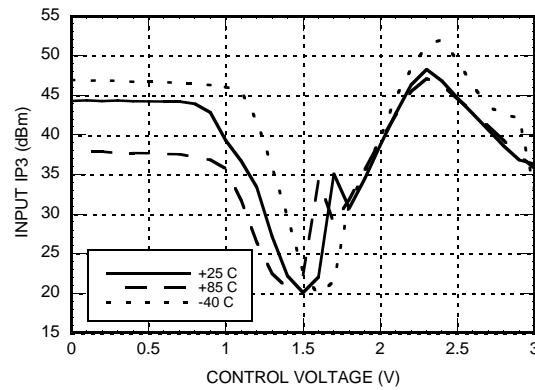
Functional Diagram



Electrical Specifications, $T_A = +25^\circ C$, $Vdd = +3.3 Vdc$, 50 Ohm System

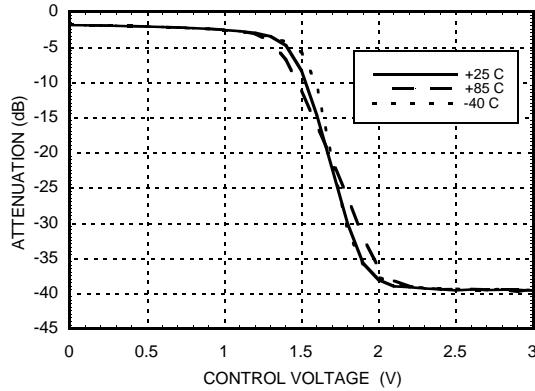
Parameter		Min.	Typ.	Max.	Units
Insertion Loss (Min. Atten.) (Vctl = 0.0 Vdc)	0.45 - 0.8 GHz 0.8 - 1.0 GHz 1.0 - 1.6 GHz 1.6 - 2.0 GHz 2.0 - 2.2 GHz		1.8 1.9 2.4 2.8 3.0	2.2 2.3 2.9 3.3 3.5	dB
Attenuation Range (Vctl = 0 to +3 V)	0.45 - 0.8 GHz 0.8 - 1.0 GHz 1.0 - 1.6 GHz 1.6 - 2.0 GHz 2.0 - 2.2 GHz	34 43 32 27 24	39 48 37 32 29		dB
Return Loss (Vctl = 0 to +3 V)	0.45 - 0.8 GHz 0.8 - 1.0 GHz 1.0 - 1.6 GHz 1.6 - 2.0 GHz 2.0 - 2.2 GHz		15 14 11 10 9		dB
Input Power for 0.1 dB Compression (0.9 GHz)	Min Atten. Atten. > 2.0		20 5.5		dBm dBm
Input Power for 1.0 dB Compression (0.9 GHz)	Min Atten. Atten. > 2.0	24 11	28 15		dBm dBm
Input Third Order Intercept (0.9 GHz, Two-tone Input Power = +5.0 dBm Each Tone)	Min Atten. Atten. > 2.0		47 20		dBm dBm
Switching Characteristics (RISE/FALL (10/90% RF) t_{ON}, t_{OFF} (50% CTL to 10/90% RF))	0.45 - 2.2 GHz		1.3 1.5		μs μs

For price, delivery, and to place orders, please contact Hittite Microwave Corporation:

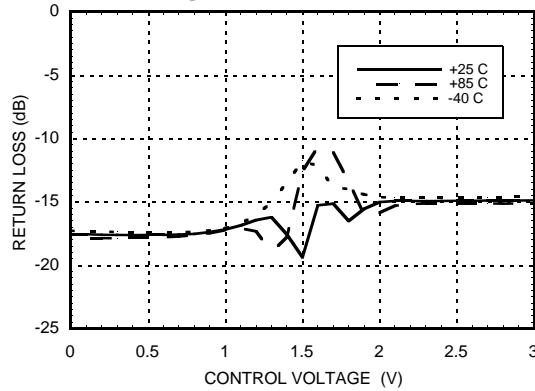
**GaAs MMIC VOLTAGE-VARIABLE
ATTENUATOR, 0.45 - 2.2 GHz**
Insertion Loss vs. Temperature**Return Loss vs. Control Voltage****Input IP3 vs. Control Voltage @ 0.45 GHz****Input IP3 vs. Control Voltage @ 0.9 GHz****Input IP3 vs. Control Voltage @ 1.9 GHz****Input IP3 vs. Control Voltage @ 2.1 GHz**

GaAs MMIC VOLTAGE-VARIABLE ATTENUATOR, 0.45 - 2.2 GHz

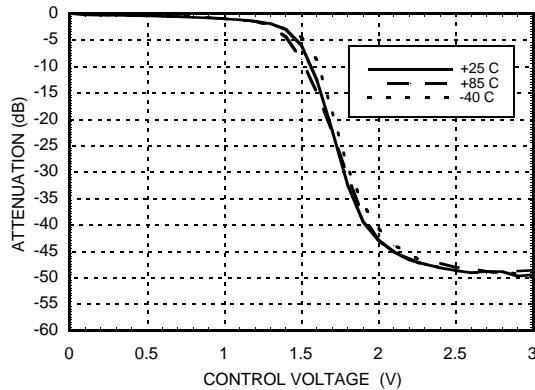
**Relative Attenuation vs.
Control Voltage @ 0.45 GHz**



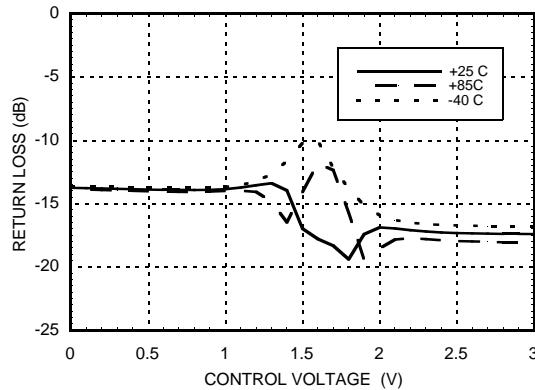
**Return Loss vs.
Control Voltage @ 0.45 GHz**



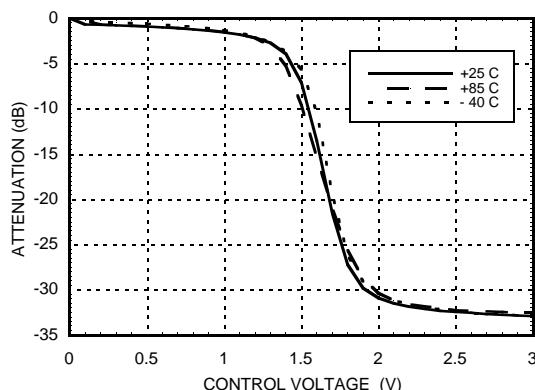
**Relative Attenuation vs.
Control Voltage @ 0.9 GHz**



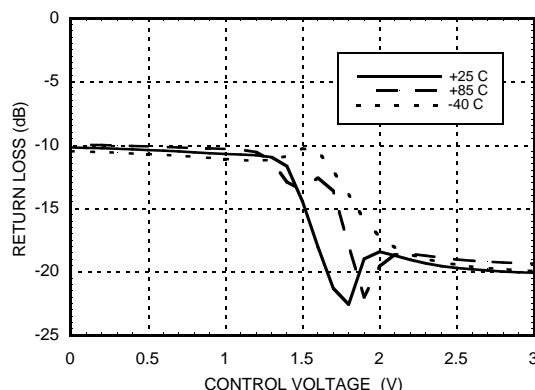
**Return Loss vs.
Control Voltage @ 0.9 GHz**



**Relative Attenuation vs.
Control Voltage @ 1.9 GHz**

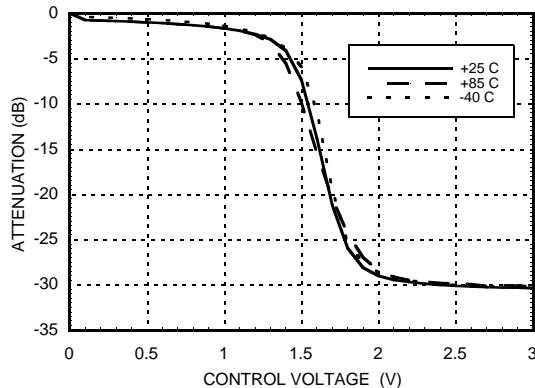


**Return Loss vs.
Control Voltage @ 1.9 GHz**

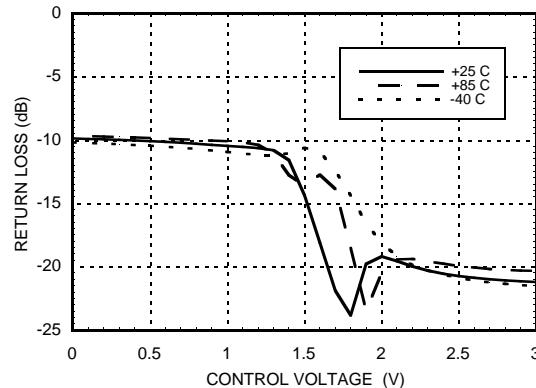


GaAs MMIC VOLTAGE-VARIABLE ATTENUATOR, 0.45 - 2.2 GHz

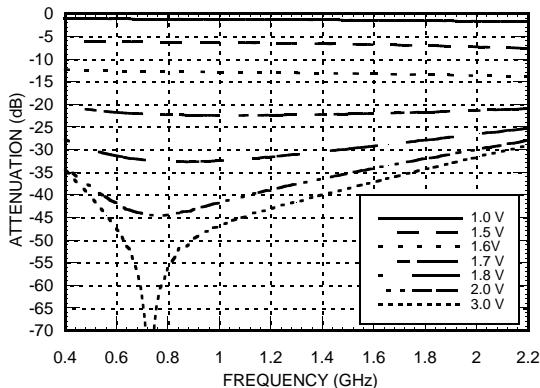
**Relative Attenuation vs.
Control Voltage @ 2.1 GHz**



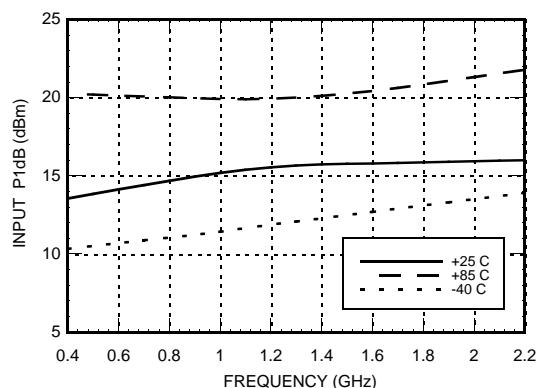
**Return Loss vs.
Control Voltage @ 2.1 GHz**



Relative Attenuation vs. Control Voltage



Worse Case Input P1dB vs. Temperature



Absolute Maximum Ratings

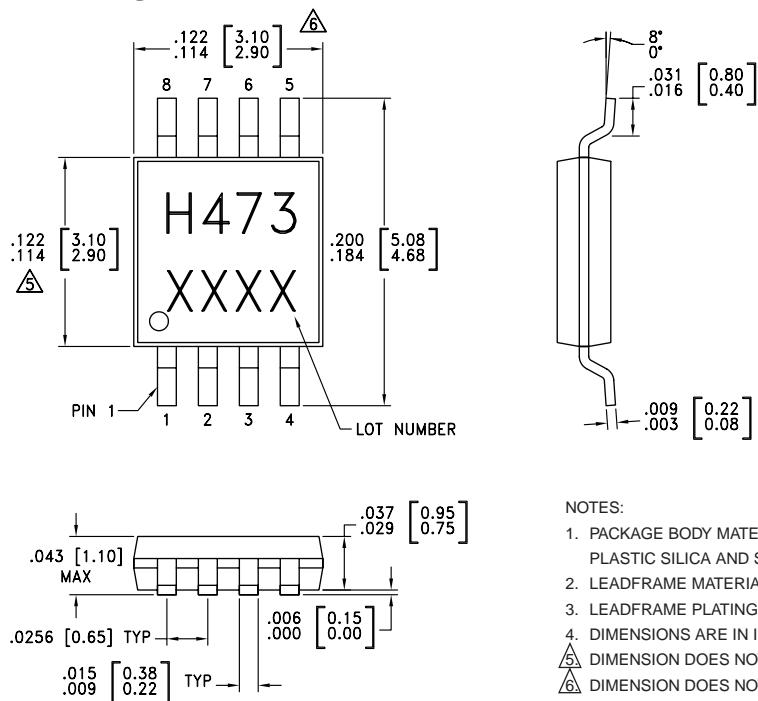
V_{CTL}	-0.2 Vdc to Vdd
Vdd	+8 Vdc
Maximum Input Power Vdd = +3.3 Vdc	+29 dBm +21 dBm
Channel Temperature (Tc)	150 °C
Thermal Resistance (R_{TH}) (junction to lead)	92 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C

Control and Bias Voltage

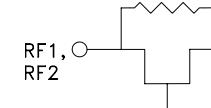
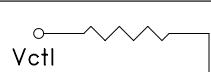
V_{CTL}	0 to +3 Vdc @ 1 μ A
Vdd	+3.3 Vdc +/- 0.1 Vdc @ 10 μ A

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Outline Drawing



Pin Descriptions

Pin Number	Function	Description	Interface Schematic
1, 8	RF1, RF2	These pins are DC coupled and matched to 50 Ohms. DC blocking capacitors are required. 330pF capacitors are supplied on evaluation board.	
2, 7	GND	Pins must connect to RF ground.	
3	Vctl	Control voltage	
4, 5	N/C	No Connection. These pins may be connected to RF ground. Performance will not be affected.	
6	Vdd	Supply Voltage.	

GaAs MMIC VOLTAGE-VARIABLE ATTENUATOR, 0.45 - 2.2 GHz

**Attenuation Linearizing Control Circuit
For The HMC473MS8 Voltage Variable Attenuator**

A driver circuit to improve the attenuation linearity of the HMC473MS8 can be implemented with a simple op-amp configuration. A *breakpoint* linearization circuit will scale the voltage supplied to the control line of the HMC473MS8, so that a more linear attenuation vs. control voltage slope can be achieved. A -3.3V and +3.3V supply is required.

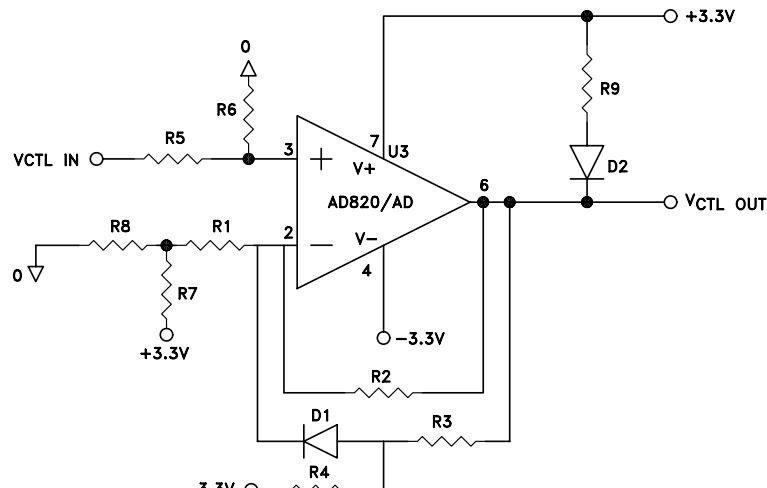
Diode and resistor values which define the op-amp gain, and breakpoint were selected to optimize a measured production lot of attenuators at 0.9 GHz. R7 may be varied to optimize the performance of any given attenuator. If the input voltage to the linearizing circuit will not drop below 1.0V, the R9 and D2 may be omitted, and this will greatly reduce the overall power consumption of the driver circuit.

The linearizing circuit has been optimized for 0.9 GHz attenuation applications. A similar approach may be used at other frequencies by adjusting R1 - R9 resistor values.

Required Parts List

Part	Description	Manufacturer
AD822	Op-Amp	Analog Devices
R1	10K ohms	Panasonic
R2	200K ohms	Panasonic
R3	7.5K ohms	Panasonic
R4	39K ohms	Panasonic
R5	220K ohms	Panasonic
R6	91K ohms	Panasonic
R7	910 ohms	Panasonic
R8	51 ohms	Panasonic
R9	100 ohms	Panasonic
D1, D2	LL4148 D-35	Digi-Key

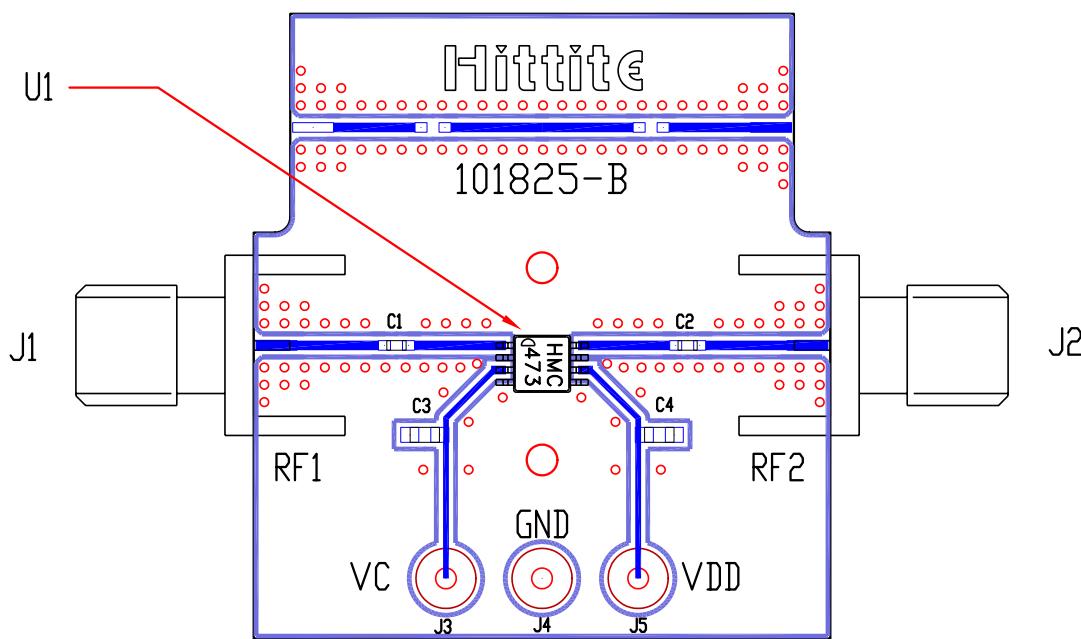
Application Circuit



**GaAs MMIC VOLTAGE-VARIABLE
ATTENUATOR, 0.45 - 2.2 GHz**
Evaluation PCB

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ATTENUATORS - SMT



The circuit board used in the final application should be generated with proper RF circuit design techniques. Signal lines at the RF ports should be 50 ohm impedance and the package ground leads should be connected directly to the PCB RF ground plane, similar to that shown above. The evaluation circuit board shown above is available from Hittite Microwave Corporation upon request.

List of Material

Item	Description
J1 - J2	PC Mount SMA RF Connector
J3 - J5	DC PIN
C1, C2	330pF capacitor, 0402 package
C3, C4	10KpF capacitor, 0603 package
U1	HMC473MS8
PCB*	101825 Eval Board

*Circuit Board Material: Rogers 4350



v00.1103

HMC473MS8

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Notes:

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ATTENUATORS - SMT